Thyristor Semiconductor Device - Page 1 of 1

AeroBase Group

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Ir	nclosure Material:
N	letal
0	verall Length:
0	405 inches
Т	erminal Length:
В	etween 0.480 inches and 0.520 inches
0	verall Height:
0	185 inches
0	verall Width:
0	.320 inches
Ir	nternal Configuration:
Jı	unction contact
Е	lectrode Internally-electrically Connected To Case:
A	node
Ν	lounting Method:
Т	erminal
F	eatures Provided:
Н	ermetically sealed case
S	emiconductor Material:
S	ilicon
v	oltage Rating In Volts Per Characteristic:
3	0.0 off-state voltage, rms total
С	urrent Rating Per Characteristic:
2	00.00 microamperes forward current, total rms preset
S	pecial Features:
J	unction pattern arrangement: pnpn
T	erminal Type And Quantity:
3	uninsulated wire lead
S	helf Life:
N	/a
U	nit Of Measure:
D	emilitarization:
Ν	0
F	iig:
	110a0